Product data sheet

1. General description

Silicon Carbide Schottky diode in a 2-lead TO247-2L plastic package, designed for high frequency switched-mode power supplies.





2. Features and benefits

- · Extremely fast reverse recovery time
- Low figure of merit (Q_C*V_F)
- · Highly stable switching performance
- Superior in efficiency to Silicon Diode alternatives
- · Reduced losses in associated MOSFET
- Reduced EMI
- · Reduced cooling requirements
- RoHS compliant

3. Applications

- · Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Val	ues		Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			12	200		V
$I_{F(AV)}$	average forward current	δ = 0.5; square-wave pulse; T _{mb} ≤ 132 °C; Fig. 1; Fig. 2; Fig. 3	10		А		
T _j	junction temperature			1	75		°C
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.42	1.65	V
		I _F = 10 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.88	2.3	V
		I _F = 10 A; T _j = 175 °C; <u>Fig. 5</u>		-	1.97	2.5	V
Dynamic	characteristics				1		1
Q_r	recovered charge	$I_F = 10 \text{ A}; \text{ d}I_F/\text{d}t = 500 \text{ A/}\mu\text{s}; \text{ V}_R = 400 \text{ V};$ $T_i = 25 ^{\circ}\text{C}; \text{ Fig. 7}$		-	25	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		V 14 A
2	А	anode		K — A 001aaa020
mb	mb	mounting base; connected to cathode	K A TO247-2L	

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC2D101200W	TO247-2L	WNSC2D101200WQ	Tube	30	TO247L-2L	10-Nov-2020

7. Marking

Table 4. Marking codes

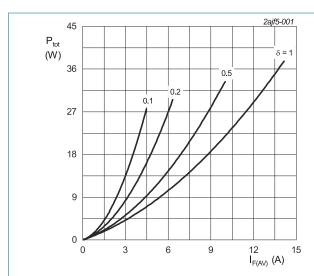
Type number	Marking codes
WNSC2D101200W	WNSC2D
	101200W

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		1200	V
V_{RWM}	crest working reverse voltage		1200	V
V_R	reverse voltage	DC	1200	V
I _{F(AV)}	average forward current	$δ$ = 0.5; square-wave pulse; $T_{mb} \le 132$ °C; Fig. 1; Fig. 2; Fig. 3	10	А
I _{FRM}	repetitive peak forward current	δ = 0.5; t_p = 25 μs; $T_{mb} \le$ 132 °C; square-wave pulse	20	А
I _{FSM}	non-repetitive peak	$t_p = 10 \text{ ms; } T_{j(init)} = 25 \text{ °C; sine-wave pulse}$	72	А
	forward current	t _p = 10 μs; T _{j(init)} = 25 °C; square-wave pulse	850	Α
l ² t	I ² t for fusing	sine-wave pulse; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$	26	A ² s
T _{stg}	storage temperature		-55 to 175	°C
T _j	junction temperature		175	°C



 $I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$ $V_o = 1.041 \text{ V; } R_s = 0.1148 \Omega$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

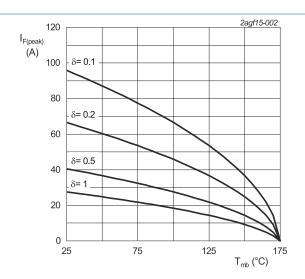
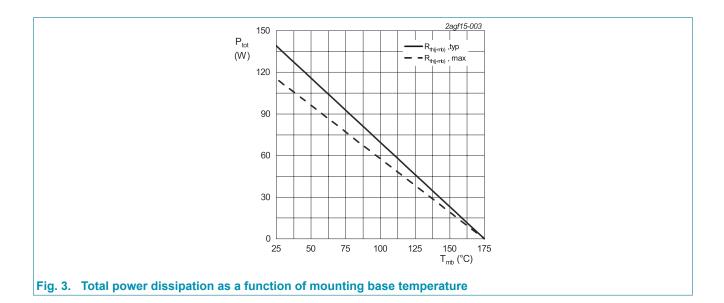


Fig. 2. Current derating as a function of mounting base temperature



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 4</u>	-	1.08	1.3	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	40	-	K/W

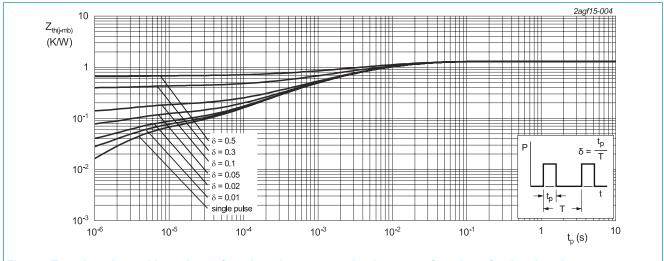
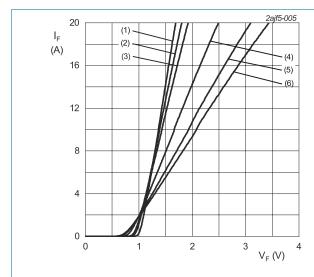


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Mir	Тур	Max	Unit
Static cha	aracteristics			'		
V _F	forward current	I _F = 10 A; T _j = 25 °C; <u>Fig. 5</u>	-	1.42	1.65	V
		I _F = 10 A; T _j = 150 °C; <u>Fig. 5</u>	-	1.88	2.3	V
		I _F = 10 A; T _j = 175 °C; <u>Fig. 5</u>	-	1.97	2.5	V
I _R	reverse current	V _R = 1200 V; T _j = 25 °C; <u>Fig. 6</u>	-	3	110	μA
		V _R = 1200 V; T _j = 175 °C; <u>Fig. 6</u>	-	60	-	μA
Dynamic	characteristics				1	
Q _r	recovered charge	$I_F = 10 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	25	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C	-	490	-	pF
		f = 1 MHz; V _R = 400 V; T _j = 25 °C	-	48	-	pF
		f = 1 MHz; V _R = 800 V; T _j = 25 °C	-	36	-	pF
E _{as}	non-repetitive avalanche energy	I _R = 4.2 A; L = 10 mH; T _{j(init)} = 25 °C	88	-	-	mJ



 V_o = 1.041 V; R_s = 0.1148 Ω

(1) $T_j = -55$ °C; typical values

(2) $T_j = 0$ °C; typical values

(3) T_i = 25 °C; typical values

(4) $T_j = 100 \, ^{\circ}\text{C}$; typical values

(5) $T_j = 150$ °C; typical values (6) $T_i = 175$ °C; typical values

Fig. 5. Forward current as a function of forward voltage; typical values

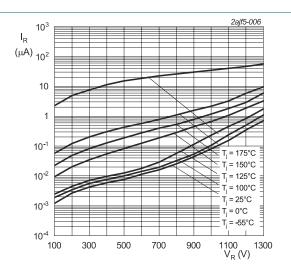
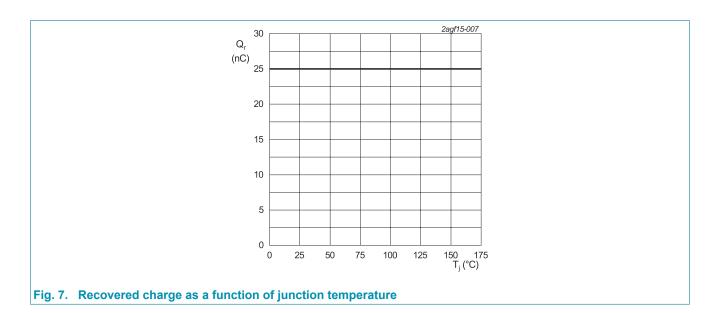
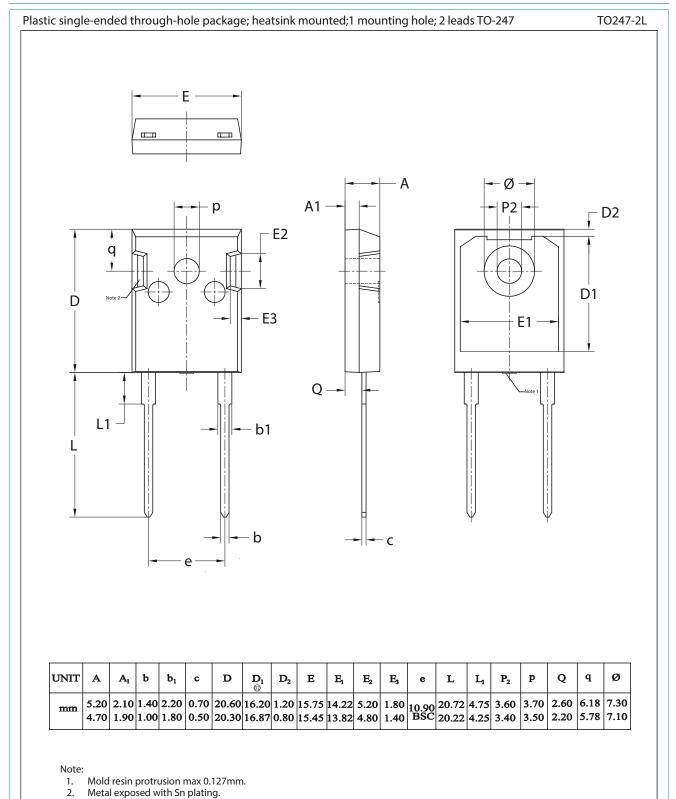


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value



11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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